

Two-Fluxon Dynamics in Annular Josephson Junction

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Two-fluxon state in an annular Josephson junction in the presence of external magnetic field is studied analytically, numerically and experimentally. We obtain an analytical expression for the potential of interaction between the fluxons moving at arbitrary velocities (without the use of the “nonrelativistic” approximation). Treating the fluxons as quasi-particles, we then derive equations of motion for them. Direct simulations of the full extended sine-Gordon equation are in good agreement with results produced by the analytical model, in a relevant parameter region. Experimental data qualitatively agree with the numerical results.

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I. INTRODUCTION

A magnetic flux quantum (fluxon) in long Josephson junction (LJJ) is a well-known physical example of a sine-Gordon soliton. Ring-shaped (annular) LLJs serve as the ideal setting to study the fluxon dynamics, as it is not perturbed by boundary conditions at edges, which is the case for linear LLJs¹. Due to the magnetic-flux quantization in a superconducting ring, the number of fluxons initially trapped in an annular junction is conserved. An effective tool, which makes it possible to create an effective spatially periodic potential for a fluxon trapped in the annular LJJ, is external dc magnetic field directed parallel to the ring’s plane². If θ is the angular fluxon coordinate along the ring, the effective potential is $U(\theta) \sim H \cos \theta$, where H is the strength of the magnetic field. The minimum of the potential is located at the spot where the fluxon’s magnetic moment is directed along the external field. The dynamics of a single fluxon in the spatially periodic potential has been an object of intensive theoretical and experimental investigations^{3,4,5,6,7,8,9,10,11}.

The objective of the present work is to study, both theoretically and experimentally, dynamics of two fluxons with equal polarities trapped in the annular LJJ. The system is schematically shown in Fig. 1. This problem is distinguished by the interplay of the above-mentioned effective periodic potential acting on each fluxon and direct interaction (repulsion) between them.

The interaction between two fluxons in LJJJs was first studied theoretically by Karpman *et al.* (see Ref. 12 and references therein). These authors found an analytic expression for the interaction force between fluxons in the case of a small relative velocity, which corresponds to the “nonrelativistic” approximation when the relative velocity is much smaller than the limit velocity in the LJJ (the Swihart velocity). However, in the situation relevant to experiment, the latter condition is not met, in the general case. In this paper, we aim to develop an analytical description of the interaction valid in the general (“relativistic”) case. The theory will be based on an asymptotic method for weakly interacting solitons in non-integrable systems^{6,13,14}. The analysis will be followed by direct

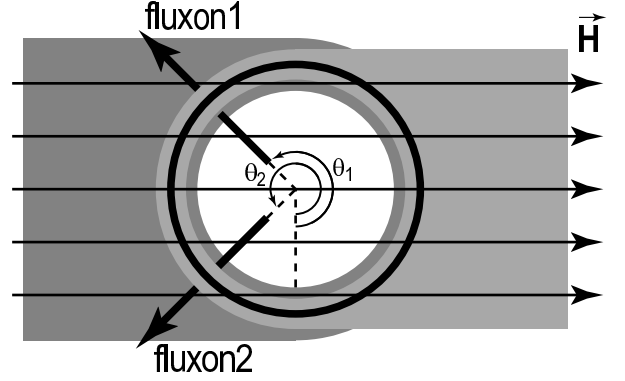


FIG. 1: The schematic view of an annular Josephson junction with two trapped fluxons; the magnetic field \vec{H} is applied in the plane of the junction. Josephson tunnel barrier is shown by thick black line; in grey are shown superconducting electrodes, which are extended in the junction plane in order to feed the bias current.

simulations and presentation of experimental results.

The theoretical model for the annular LJJ in the external magnetic field was proposed in Ref.². It is based on the following extended (perturbed) sine-Gordon (sG) equation for the superconducting phase difference φ between electrodes of the junction:

$$\varphi_{xx} - \varphi_{tt} - \sin \varphi = \alpha \varphi_t + \gamma + h \sin(qx). \quad (1)$$

Here x is the coordinate along the ring, which is normalized to the Josephson penetration depth λ_J , the time t is normalized to the inverse plasma frequency ω_0^{-1} , α is a dissipation coefficient due to the quasiparticle tunnelling across the junction, and γ is the bias current density (which is necessary in order to compensate losses due to dissipation), normalized to the critical current density j_c of the junction. As usually, the bias current is assumed to be uniformly distributed along the ring. Further, $q \equiv 2\pi/L$, where L is the normalized circumference of the junction, and h is the strength of the external magnetic field H , normalized by a sample-specific geometric factor^{2,8}. If N fluxons are trapped in the ring, Eq. (1) is

supplemented by the boundary condition

$$\varphi(L + x, t) = \varphi(x, t) + 2\pi N.$$

The paper is organized as following. The single-fluxon dynamics in the annular LJJ is reviewed in Sec. II A. In Sec. II B, the derivation of an effective force of interaction between two fluxons, valid in the general (relativistic) case, is presented. Result of numerical calculations are displayed in Sec. III. In Sec. III A, we analytically consider a special case of an ostensible resonance in the two-fluxon system. In Sec. IV, we present experimental results for two fluxons trapped in an annular LJJ.

II. THEORY

A. The basic model

In our theoretical approach, we assume, as it is usually done, that the fluxons are well separated from each other, $|\xi_1 - \xi_2| \gg 1$, where $\xi_{1,2}$ are coordinates of their centers. In this case the two-soliton state may be represented by a linear combination of two single-soliton solutions:

$$\varphi = \varphi_1 + \varphi_2, \quad (2)$$

where

$$\varphi_n = 4 \arctan \exp \left(-\frac{x - \xi_n(t)}{\sqrt{1 - \dot{\xi}_n^2}} \right) + 2\pi(n - 1) \quad (3)$$

is the single-soliton solution of the unperturbed sG equation, and $\dot{\xi}_n$ is the velocity of the n -th soliton. The last term in Eq. (3) is an arbitrary shift of the background phase (which is always possible if it is a multiple of 2π), which is chosen for convenience in what follows below.

Before discussing the interaction of two fluxons, we briefly recall known results for a single fluxon trapped in an annular LJJ. This fluxon may be considered as a quasiparticle obeying the well-known equation of motion^{3,15}:

$$\frac{d}{dt} \left(\frac{\dot{\xi}}{\sqrt{1 - \dot{\xi}^2}} \right) + \frac{\alpha \dot{\xi}}{\sqrt{1 - \dot{\xi}^2}} + \frac{\pi h}{4} \operatorname{sech} \left(\frac{\pi^2}{L} \right) \sin(q\xi) = \frac{\pi\gamma}{4}. \quad (4)$$

It is tantamount to the equation of motion for a relativistic pendulum in a lossy medium under the action of constant torque. This equation has solutions of two types. The first type gives rise to $|\xi(t)|$ growing infinitely. It describes progressive motion (rotation) of the fluxon around the ring, with a nonzero mean value of the velocity $\dot{\xi}$. Solutions of the second type correspond to small oscillations of the fluxon around the minimum of the effective potential with the frequency

$$\omega_0 = \left[\frac{\pi^2}{2L} \operatorname{sech} \left(\frac{\pi^2}{L} \right) \sqrt{h^2 - \gamma^2 \cosh \left(\frac{\pi^2}{L} \right)} \right]^{1/2}, \quad (5)$$

the average velocity being zero. This state exists if $|\gamma|$ is below the critical value,

$$\gamma_c^{(1)} = h \operatorname{sech} \left(\frac{\pi^2}{L} \right). \quad (6)$$

In the presence of dissipation ($\alpha \neq 0$), the oscillations are damped, and in the stationary state the fluxon is at rest. On the other hand, the progressive motion remains possible if the dissipation is not too strong. The fluxon moves with the average velocity, which, in the first approximation, is given by the McLaughlin-Scott formula³,

$$\langle \dot{\xi}_0 \rangle = \left(1 + \frac{4\alpha}{\pi\gamma} \right)^{-1/2}. \quad (7)$$

Equation (7) determines the current-voltage characteristics of the junction with a single trapped fluxon.

In the case of two trapped fluxons, we assume that they are quasiparticles interacting with a certain force (see below), and all the forces in Eq. (4) act on each fluxon separately. In this case, three different dynamical regimes are expected: (i) oscillations of both fluxons (“O-O” regime, i.e., a zero-voltage state), (ii) rotation of both fluxons (“R-R” regime), (iii) rotation of one fluxon and oscillations of the other one (“R-O” regime). Note that in R-O regime oscillations take place even in the presence of dissipation, because the fluxon whose average velocity is zero is periodically excited by collisions with the rotating one. All the regimes are implied to be quasi-stationary states due to the stabilized effect of the dissipation.

B. The interaction force

In order to find the interaction force between two fluxons, we use the center-of-mass reference frame (C-frame). In this frame, the two solitons move with velocities $\pm u$, where

$$u = \frac{1 - \dot{\xi}_1 \dot{\xi}_2 - \sqrt{1 - \dot{\xi}_1^2} \sqrt{1 - \dot{\xi}_2^2}}{\dot{\xi}_1 - \dot{\xi}_2}.$$

In the subsequent calculation, we set $\xi_1 < \xi_2$.

To calculate an effective potential of the interaction between fluxons, which will then produce the interaction force, we start with the Hamiltonian of the unperturbed sG equation for the infinitely long system:

$$H = \int_{-\infty}^{\infty} dx \left(\frac{1}{2} \varphi_t^2 + \frac{1}{2} \varphi_x^2 + 1 - \cos \varphi \right). \quad (8)$$

For the calculation of the Hamiltonian (8), we divide the space into two parts. The left (right) part occupies the space from $-\infty$ ($+\infty$) to the midpoint between the two fluxons, $a \equiv (\xi_1 + \xi_2)/2$. We perform the actual calculation for the left part only, as for the right part the calculation is quite similar.

In the left part, we substitute the solution as the linear combination (2), where φ_2 is considered as a small perturbation, as the two fluxons are assumed to be well separated. Then, the Hamiltonian is written, in the first approximation, as

$$H_{\text{left}} = H_1 + \delta H_{\text{left,int}},$$

where $H_1 = 8/\sqrt{1-u^2}$ is the Hamiltonian of the unperturbed sG soliton, and the interaction term is of the first order with respect to the weak field φ_2 ,

$$\delta H_{\text{left,int}} = \int_{-\infty}^a dx (\varphi_{1,x}\varphi_{2,x} + \varphi_{1,t}\varphi_{2,t} + \varphi_2 \sin \varphi_1) \quad (9)$$

(recall the subscripts x and t stand for the corresponding partial derivatives). Substituting the expression valid for a moving soliton, $\varphi_{n,t} = -\dot{\xi}\varphi_{n,x}$, and integrating by parts, we obtain

$$\begin{aligned} \delta H_{\text{left,int}} &= (1-u^2)\varphi_{1,x}\varphi_2|_{-\infty}^a + \\ &+ \int_{-\infty}^a dx \varphi_2 (-\varphi_{1,xx} + \varphi_{1,tt} + \sin \varphi_1). \quad (10) \end{aligned}$$

The integral term in Eq. (10) is zero as the bracketed expression is the sine-Gordon equation proper (this way to nullify the integral terms is known in the general analysis of the interaction between separated solitons¹⁴). The contribution to the first term in Eq. (10) at the left limit, $x = -\infty$, is zero too because both $\varphi_{1,x}$ and φ_2 decay exponentially at infinity. In order to calculate the contribution from the upper limit, we use the asymptotic form of $\varphi_{1,x}$ (φ_2) at large values of x (which is also a known point in the general analysis of the soliton-soliton interaction¹⁴):

$$\begin{aligned} \varphi_{1,x} &= -\frac{4}{\sqrt{1-u^2}} \exp\left(-\frac{x-\xi_1}{\sqrt{1-u^2}}\right), \\ \varphi_2 &= -4 \exp\left(\frac{x-\xi_2}{\sqrt{1-u^2}}\right). \quad (11) \end{aligned}$$

After the substitution of the expressions (11) into Eq. (10) and calculation of the nonvanishing contribution to the first term from the right limit, $x = a$, and then getting back from the C-frame to the laboratory reference frame (L-frame), we arrive at an expression for the interaction potential for two moving fluxons in the infinitely long junction,

$$\delta H_{\text{int}} = 32 \frac{\sqrt{1-u^2}}{\sqrt{1-V^2}} \exp\left(-\frac{|\xi_1-\xi_2|}{\sqrt{1-u^2}}\right), \quad (12)$$

where the contribution of the right half space is taken into account and

$$V = \frac{1 + \dot{\xi}_1 \dot{\xi}_2 - \sqrt{1-\dot{\xi}_1^2} \sqrt{1-\dot{\xi}_2^2}}{\dot{\xi}_1 + \dot{\xi}_2} \quad (13)$$

is the velocity of the center-of-mass of the two-fluxon set in L-frame. In the case of equal velocities, the potential (12) reduces to the well-known result of Karpman *et al.*¹².

The potential (12) gives rise to two forces acting on each soliton, due to the ring geometry of the system, which should be added to the individual forces in Eq. (4),

$$\begin{aligned} (F_{\text{int}})_1 &= -(F_{\text{int}})_2 = -\frac{1}{8} \frac{d}{d\Delta x} \delta H_{\text{int}}^{\text{ring}} = \\ &= \frac{4}{\sqrt{1-V^2}} \left[\exp\left(-\frac{\Delta X}{1-u^2}\right) - \exp\left(-\frac{L-\Delta X}{1-u^2}\right) \right], \quad (14) \end{aligned}$$

where $\Delta X = |\xi_1 - \xi_2|$, and 8 is for the effective mass of the fluxon in the present notation. Equations (4) and (14) describe the dynamics of the two-fluxon system in an annular LJJ. These equations of motion we solved numerically by means of the fourth-order Runge-Kutta method.

III. NUMERICAL CALCULATIONS

In order to verify the theory presented above, we checked numerical solutions of the quasi-particle equations of motion against direct simulations of the full equation (1). Here we present results for fixed values $\alpha = 0.02$ and $L = 20$, while the bias current γ was varied in steps of 0.002.

The general behavior of the system can be described as the following. While γ increases from zero, both fluxons originally stay pinned in the effective potential induced by the magnetic field, so that the voltage across the junction is zero. At a critical value of the current γ_c , the system switches to the R-O regime, in which one of the fluxons rotates, while the other one oscillates due to periodic collisions with the moving fluxon. This state is stable up to another critical point, $\gamma < \gamma_s$. On the other hand, decreasing the bias current leads to a transition to the regime with both fluxons pinned (zero voltage) at a different value, $\gamma = \gamma_r$.

At $\gamma > \gamma_s$, the system operates in R-R regime with both fluxons rotating. Further increase of the bias current does not change the state of the system, up to a large value of the current, at which the junction switches to the “whirling” (alias resistive) state, with uniform rotation of the phase in all the system. When decreasing the bias current, the system switches first to the R-O regime, and then to the zero-voltage state.

Typical current-voltage (I-V) characteristics, which display all these states and transitions, are presented in Fig. 2. Points shown by dots correspond to the numerical solution of the full equation (1), while the lines depict solutions of the quasi-particle model based on Eqs. (4) and (14). As is seen, the analytical quasi-particle model making use of the expression (14) for the interaction forces is in good agreement with direct simulations.

The comparison of the critical values γ_c of the bias current, obtained from the full simulations and from the

analytical model, is shown in Fig. 3. A small difference between them can be attributed to the fact that, in the O-O regime, the actual distance between the pinned fluxons is small, hence the assumption of far separated fluxons does not apply in this case. Indeed the numerical simulations show that the distance between the fluxons in static case changes, depending on the magnetic field, in range of 0.8 – 1.5.

For small currents, the I-V curve of the R-O and R-R regimes, found from the direct simulations of Eq. (1), feature additional small steps, which are due to resonant generation of radiation by the fluxons moving in the periodic potential⁷.

The comparison of the other critical value of the bias current, γ_s (which corresponds to the first step of the I-V characteristics), again as found from the direct simulations and analytical model, is shown, versus the magnetic field, in Fig. 4. At small values of the magnetic field, these dependencies agree very well. However, for $h > 0.45$ the curve generated by the direct simulations goes down with the increase of the field. Actually, in this region the parameters γ and h are too large to apply the perturbation theory. With the further increase of h , γ_s decreases until it becomes equal to γ_c . For a still stronger field, the system switches from the O-O regime directly to the whirling state.

On the other hand, the curve produced by the analytical approximation continues to go up with the field until $h = 0.5$. For fields larger than 0.5, the system resonantly switches from the R-O regime to the R-R one, but at so large values of the field the quasi-particle model based on the perturbation theory becomes completely irrelevant.

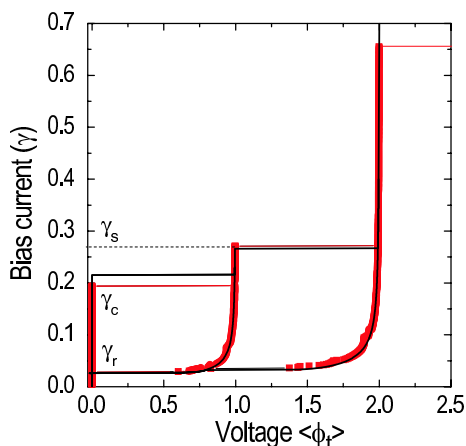


FIG. 2: The current-voltage characteristics of the long annular junction with two trapped fluxons found from direct numerical simulation of Eq. (1) (dots), and from the analytical model based on Eq. (4) and (14) (solid line). In this case, the magnetic field is fixed to $h = 0.3$.

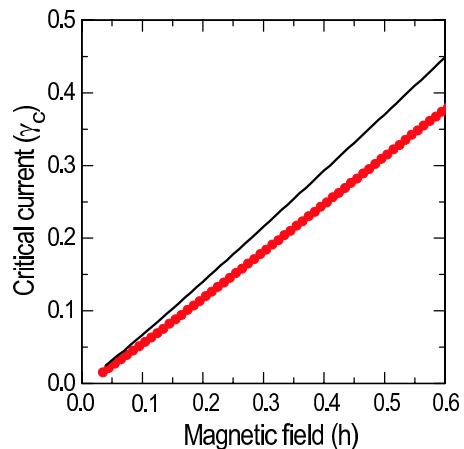


FIG. 3: The critical current γ_c versus the magnetic field h , obtained from direct numerical simulations of the full equation (1) (dots) and from the quasi-particle model (line).

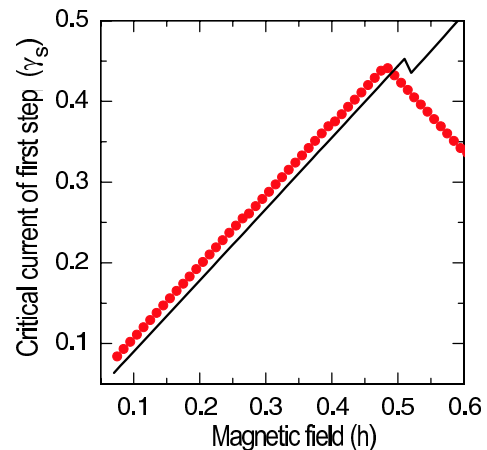


FIG. 4: The dependence of the maximum current of the first step in the I-V curve, γ_s , on the magnetic field h , as found from direct simulations of the full equation (1) (dots), and from the analytical model based on Eqs. (4) and (14) (line).

A. A resonance condition

An noteworthy feature of the two-fluxon dynamics in the R-O regime is a possibility of a resonance between the natural frequency of oscillations of the trapped fluxon, and periodic excitation due to its collisions with the rotating one. The resonance condition is obtained by equating the frequency of small oscillations ω_0 , given by Eq. (5), and the rotation frequency $\omega_r = q < \xi_r >$, where ξ_r is the velocity of the rotating fluxon, which can be obtained from Eq. (7). This yields

$$h = \gamma_{\text{res}} \cosh\left(\frac{\pi^2}{L}\right) \sqrt{1 + \frac{64\pi^2}{L^2(\pi\gamma_{\text{res}} + 4\alpha)^2}}, \quad (15)$$

where γ_{res} is the value of the bias current corresponding to the resonance.

This dependence for $L = 20$ and $\alpha = 0.02$ is plotted in Fig. 5 by dots. The line corresponds to the critical

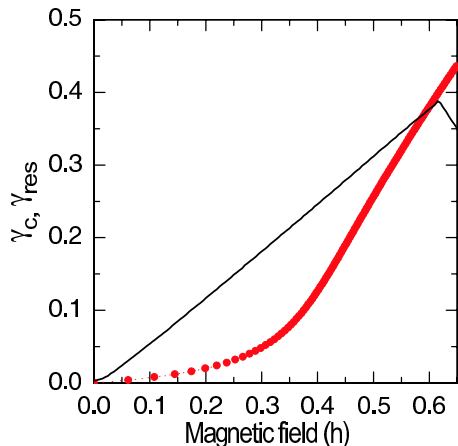


FIG. 5: Critical current of two fluxon state found from numerical solutions of Eq. (1) (solid line) and the current of expected resonance (dots)

current of the two fluxon state found from full numerical simulations of Eq. (1) for the same length. It may be expected that this resonance would result in a resonant switching from R-O to R-R regime and drop of the critical current of the first step γ_s vs. magnetic field h . However, at low magnetic fields the system switches to the R-O branch at higher current than the current corresponding to the resonance. At large magnetic field it switches directly to R-R branch, because the total perturbation (field + bias current) is too strong. Here the perturbation approach is not any more applicable; the numerical solution of the analytical model reflects the resonance behavior by a drop on $\gamma_s(h)$ dependence (solid line in Fig. 4). With increase of the junction length L the intersection point of the curves $\gamma_c(h)$ and $\gamma_{res}(h)$ moves upward in bias current, while its dependence on magnetic field is very weak.

IV. EXPERIMENT

Measurements of the I-V characteristics of the two-fluxon state were performed in long annular Nb-Al-AlO_x-Nb junctions. Due to the magnetic flux quantization in a superconducting ring, the number of initially trapped fluxons (solitons) is conserved. Trapping of a magnetic flux in the junction was achieved while cooling the sample below the critical temperature $T_c^{\text{Nb}} = 9.2$ K of niobium, in the presence of a small bias current passing through the junction. The number of trapped fluxons was determined from the highest voltage of the highest resonant branch on the current-voltage characteristics (Fig. 6). Experiments were performed by applying the bias current I from top to the bottom electrode of the junction and measuring the dc voltage generated due to the motion (*rotation*, in terms of the theoretical consid-

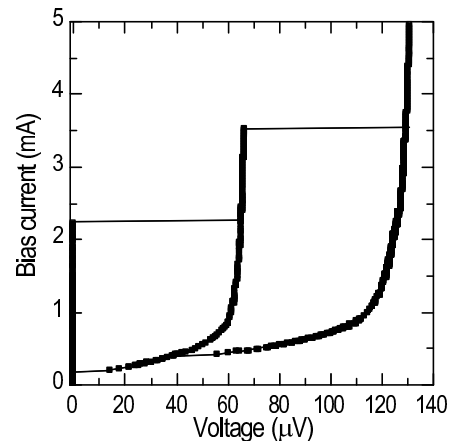


FIG. 6: Current-voltage characteristics of the annular Josephson junction with two trapped fluxons.

eration) of the trapped fluxons. The results presented below were obtained for a junction with the mean diameter $100 \mu\text{m}$ and ring's width $3 \mu\text{m}$. The circumference (length of the annular junction) in the normalized units was $L = 28.5$, and the effective loss parameter was estimated as $\alpha = 0.03$. The measurements were performed at 4.2 K.

At zero magnetic field, depinning of a single-fluxon was observed, as a switching from the zero voltage state to the single-fluxon step of the I-V curve (in the state with one trapped fluxon), at the current I_c that was smaller by a factor ≈ 65 than the critical current for the same junction, measured without trapped fluxons. This fact indicates a high degree of homogeneity of the junction (a strong local inhomogeneity would give rise to a much larger value of the fluxon-depinning critical current).

We measured I-V curves of the state with two trapped fluxons for different strengths of the applied magnetic field. One of these curves is shown in Fig. 6. The experimental curves qualitatively agree with our analysis illustrated by Fig. 2. Two branches of the I-V curve are observed. The first branch, at around $65 \mu\text{V}$ corresponds to the R-O regime and the second one at about $130 \mu\text{V}$ to R-R regime.

Figure 7 shows the measured value of the switching current for the transition from the R-O regime to the R-R one, versus the external magnetic field. The curve is quite similar to the calculated dependence $\gamma_s(h)$ (dots in Fig. 4), which was obtained above from direct integration of the full sine-Gordon model (1).

V. SUMMARY

We have reported results of theoretical and experimental studies of two-fluxon dynamics in an long annular Josephson junction in presence of the external magnetic field. An analytical expression for the interaction force between two fluxons moving at different arbitrary veloci-

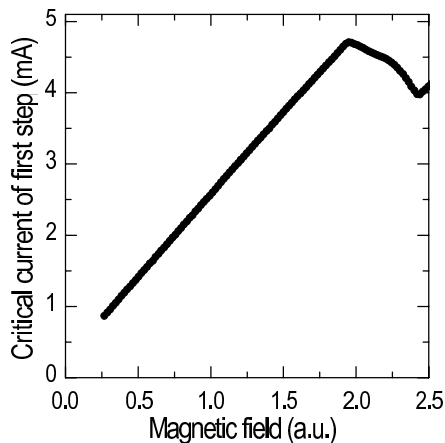


FIG. 7: The experimentally found critical current for the jump from the one-fluxon step of the I-V curve to the two-fluxon one, as a function of the magnetic field.

ties has been derived. Solution of the system of two coupled quasi-particle equations of motion for the fluxons, taking into account the interaction force, demonstrates good agreement with direct numerical simulations of the two-fluxon state in the full sine-Gordon model including all the perturbation factors.

Three distinct dynamical regimes of the two-fluxon state have been thus identified. First, both fluxons may be pinned in the potential induced by the magnetic field. There is some discrepancy in the prediction of the critical current, which destroys this static regime, between the

quasi-particle model and direct simulations, due to the fact that the separation between the two trapped fluxons is rather small, while the analytical model assumes them to be well separated.

In the second regime, one of the fluxons rotates around the junction, while the other one oscillates in the potential well. For this (R-O) regime, the maximum current is very accurately predicted by the quasi-particle model, if compared to direct numerical results. For this case, we have also investigated the possibility of the resonant excitation of the trapped fluxon by periodic collisions with the rotating one.

In the third regime, both fluxons rotate. The corresponding I-V curves found by direct simulations demonstrate several additional small steps, which are due to resonant generation of small-amplitude plasma waves by fluxons moving in the periodic potential, which has been analyzed earlier⁷ for the single-fluxon case.

The method developed in this work to calculate, in the general case, the effective interaction force acting between two moving solitons, may find application to other soliton-bearing systems.

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